

L Number	Hits	Search Text	DB	Time stamp
2	21	(etch near3 stop) with (InAlAs or GaInAlAs)	USPAT; US-PGPUB	2004/08/04 12:53
-	31	(semiconductor) same passive same active same (well near3 layers) same quantum\$4	USPAT; US-PGPUB	2004/08/04 12:53
-	4	(semiconductor) same passive same active same (well near3 layers) same quantum\$4 same etch\$4	USPAT; US-PGPUB	2004/07/23 14:50
-	157	(semiconductor) same (well near3 layers) same quantum\$4 same etch\$4	USPAT; US-PGPUB	2004/07/23 16:05
-	0	(spatically near3 separate\$4) and ((well near3 layers) same quantum\$4 same etch\$4)	USPAT; US-PGPUB	2004/07/23 15:07
-	16	(spatial\$4 near3 separate\$4) and ((well near3 layers) same quantum\$4 same etch\$4)	USPAT; US-PGPUB	2004/07/23 15:09
-	25	(spatial\$4 near3 separate\$4) and ((well near3 layers) same etch\$4)	USPAT; US-PGPUB	2004/07/23 15:10
-	327	laser\$4 same modulat\$4 same amplifi\$4 same substrate\$4	USPAT; US-PGPUB	2004/07/23 15:11
-	30	laser\$4 same modulat\$4 same amplifi\$4 same substrate\$4 same passive	USPAT; US-PGPUB	2004/07/23 15:43
-	0	6771869.pn.	USPAT; US-PGPUB	2004/07/23 15:44
-	1	"20030198451"	USPAT; US-PGPUB	2004/07/23 15:44
-	4570	semiconductor same passive same active	USPAT; US-PGPUB	2004/07/23 16:06
-	288	(semiconductor same passive same active ) and 385/\$.ccls.	USPAT; US-PGPUB	2004/07/23 16:57
-	157	385/14.ccls. and (modulat\$4 same amplif\$4 same laser\$4)	USPAT; US-PGPUB	2004/07/23 16:58
-	126	(385/14.ccls. and (modulat\$4 same amplif\$4 same laser\$4)) and semiconductor	USPAT; US-PGPUB	2004/07/23 16:58